NSN 5961-00-112-4305

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-112-4305 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 2.0 breakdown voltage, emitter-to-base, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 1.50 amperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin **Specification Data:** 80131-release4538 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**